

L Number	Hits	Search Text	DB	Time stamp
21	48	4631416.URPN.	USPAT	2004/04/28 18:27
58	5	5182455.URPN.	USPAT	2004/04/28 18:44
59	15942	((356/399,400,401,388,614).CCLS.) ((250/492.2,491.1,548,559.29,559.3,559.36).CCLS.) ((355/53,55,67,77).CCLS.) ((430/22,30,5).CCLS.) ((382/151).CCLS.) ((align\$ near spot beam)) same (wafer semiconduct\$ substrate)	USPAT; US-PPGPUB	2004/04/28 18:46
60	762	((356/399,400,401,388,614).CCLS.) ((250/492.2,491.1,548,559.29,559.3,559.36).CCLS.) ((355/53,55,67,77).CCLS.) ((430/22,30,5).CCLS.) ((382/151).CCLS.) ((438/401).CCLS.)) and ((align\$ near spot beam)) same (wafer semiconduct\$ substrate)	USPAT	2004/04/28 18:47
61	288	((356/399,400,401,388,614).CCLS.) ((250/492.2,491.1,548,559.29,559.3,559.36).CCLS.) ((355/53,55,67,77).CCLS.) ((430/22,30,5).CCLS.) ((382/151).CCLS.) ((438/401).CCLS.)) and ((align\$ near spot beam)) same (wafer semiconduct\$ substrate)	USPAT	2004/04/28 18:47
62	48	\$align\$near (spot beam) same (wafer semiconduct\$ substrate) same phase	USPAT	2004/04/28 18:48
63	1043	(align\$ near (spot beam)) same (wafer semiconduct\$ substrate)	USPAT; US-PPGPUB	2004/04/28 19:15
64	353	((356/399,400,401,388,614).CCLS.) ((250/492.2,491.1,548,559.29,559.3,559.36).CCLS.) ((355/53,55,67,77).CCLS.) ((430/22,30,5).CCLS.) ((382/151).CCLS.) ((438/401).CCLS.)) and ((align\$ near spot beam)) same (wafer semiconduct\$ substrate)	USPAT; US-PPGPUB	2004/04/28 18:47
65	60	\$align\$near (spot beam) same (wafer semiconduct\$ substrate) same phase	USPAT; US-PPGPUB	2004/04/28 19:15
66	374	(align\$ near (spot beam)) same (wafer semiconduct\$ substrate)	EPO; JPO; DERWENT; IBM_TDB	2004/04/28 19:10
67	13	((align\$ near (spot beam)) same (wafer semiconduct\$ substrate)) and phase	EPO; JPO; DERWENT; IBM_TDB	2004/04/28 19:03
68	23	(align\$ near spot) same (wafer semiconduct\$ substrate)	EPO; JPO; DERWENT; IBM_TDB	2004/04/28 19:11
69	1	2003-492470.NRAN.	DERWENT	2004/04/28 19:14
70	88	(align\$ near spot) same (wafer semiconduct\$ substrate)	USPAT; US-PPGPUB	2004/04/28 19:15
71	436	((align\$ near (spot beam)) same (wafer semiconduct\$ substrate)) and phase	USPAT; US-PPGPUB	2004/04/28 19:15
72	155	((356/399,400,401,388,614).CCLS.) ((250/492.2,491.1,548,559.29,559.3,559.36).CCLS.) ((355/53,55,67,77).CCLS.) ((430/22,30,5).CCLS.) ((382/151).CCLS.) ((438/401).CCLS.)) and ((align\$ near spot beam)) same (wafer semiconduct\$ substrate)	USPAT; US-PPGPUB	2004/04/28 19:16
73	237	\$align\$near (spot beam) same (wafer semiconduct\$ substrate) (((356/399,400,401,388,614).CCLS.) ((250/492.2,491.1,548,559.29,559.3,559.36).CCLS.) ((355/53,55,67,77).CCLS.) ((430/22,30,5).CCLS.) ((382/151).CCLS.) ((438/401).CCLS.)) and ((align\$ near spot beam)) same (wafer semiconduct\$ substrate))) and phase	USPAT; US-PPGPUB	2004/04/28 19:16